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RECTIFIERS

High Efficiency, 30A Center-Tap

UES2601
UES2602
UES2603
UES2601HR2
UES2602HR2
UES2603HR2

FEATURES

- Very Low Forward Voltage
- Very Fast Switching Speed
- Convenient Package
- High Surge
- Low Thermal Resistance
- Mechanically Rugged
- Both Polarities Available

DESCRIPTION

This series combines two high efficiency devices into one package, simplifying installation, reducing heat sink requirements and the need to purchase matched components.

ABSOLUTE MAXIMUM RATINGS

Peak Inverse Voltage, UES2601, UES2601HR2	50V
Peak Inverse Voltage, UES2602, UES2602HR2	100V
Peak Inverse Voltage, UES2603, UES2603HR2	150V
Maximum Average D.C. Output Current at $T_C = 100^\circ\text{C}$	30A
Non-Repetitive Sinusoidal Surge Current 8.3 ms	400A
Thermal Resistance, Junction to Case	1°C/W
Operating and Storage Temperature Range	-55°C to $+175^\circ\text{C}$

POWER CYCLING

These devices possess the unique ability to pass many thousands of cycles of a stress test designed to evaluate the integrity of the bonding systems used in the construction of power rectifiers.

In this stress test, the case of the device is not heat sunk. Full rated forward current is supplied to force a case temperature increase at least 75°C , at which time, the current is removed and the case allowed to cool. The cycle is repeated a minimum of 5,000 times to simulate equipment being turned on and off. Extended power cycling tests demonstrate a product capability in excess of 25,000 cycles.

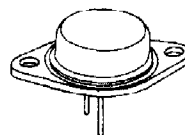
SWITCHING CHARACTERISTICS

The switching times of these ultra-fast rectifiers increase relatively little, with temperature or at different currents. Even in severe applications, such as catch diodes for switching regulators and output rectifiers for high frequency square wave inverters, these devices switch many times faster than the fastest associated transistors. Thus, the stresses on and powers dissipated in the switching transistors are substantially less than when using other rectifiers.

MECHANICAL SPECIFICATIONS

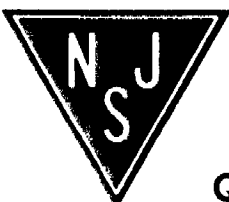
	UES2601 UES2601HR2		UES2602 UES2602HR2		UES2603 UES2603HR2	
	ins.		ins.		mm.	
A	.875 MAX.		.875 MAX.		22.23 MAX.	
B	.135 MAX.		.135 MAX.		3.43 MAX.	
C	250-450		250-450		6.35-11.43	
D	312 MIN.		312 MIN.		7.92 MIN.	
E	.038-.043 DIA.		.038-.043 DIA.		0.97-1.09 DIA.	
F	.188 MAX. RAD.		.188 MAX. RAD.		4.78 MAX. RAD.	
G	1.177-1.197		1.177-1.197		29.90-30.40	
H	.655-.675		.655-.675		16.64-17.15	
J	.205-.225		.205-.225		5.21-5.72	
K	.420-.440		.420-.440		10.67-11.18	
L	.525 MAX. RAD.		.525 MAX. RAD.		13.34 MAX. RAD.	
M	.151-.161 DIA.		.151-.161 DIA.		3.84-4.09 DIA.	

TO-204AA (TO-3)



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Quality Semi-Conductors

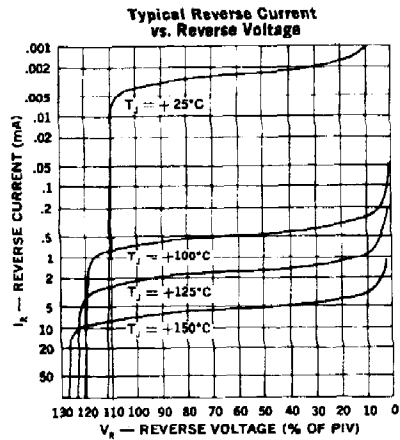
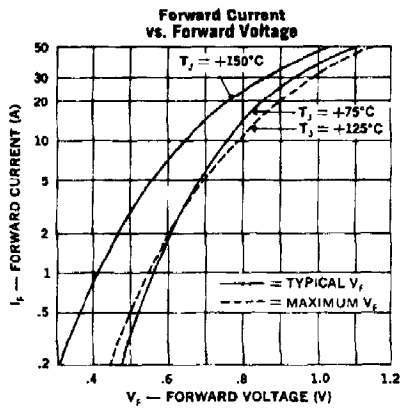
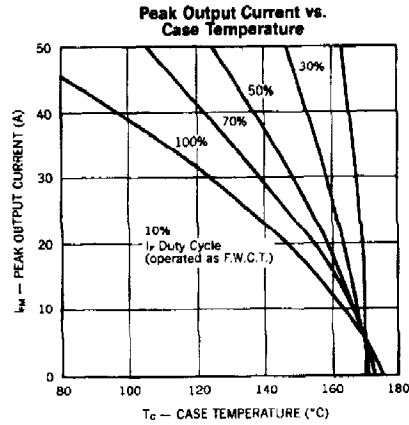
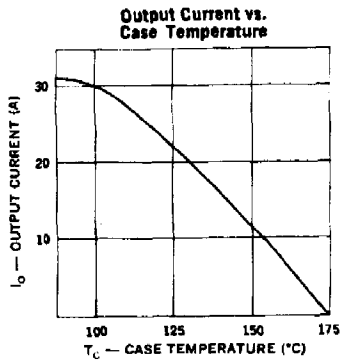


UES2601 UES2602 UES2603
UES2601HR2 UES2602HR2 UES2603HR2

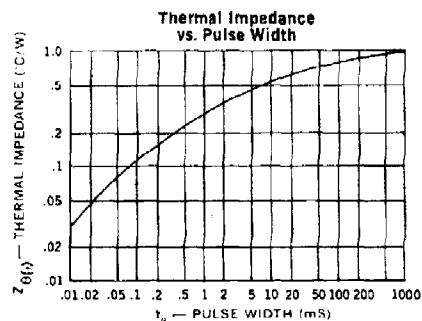
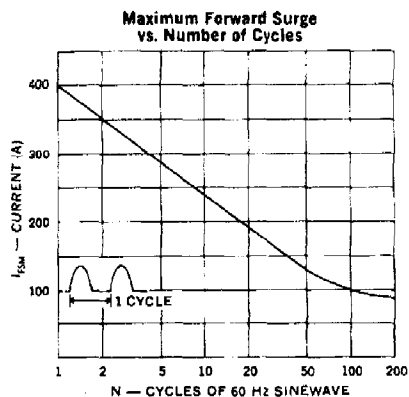
ELECTRICAL SPECIFICATIONS

Type	PIV	Maximum Forward Voltage @		Maximum Reverse Current @		Maximum Reverse Recovery Time*
		$T_C = 25^\circ\text{C}$	$T_C = 125^\circ\text{C}$	$T_C = 25^\circ\text{C}$	$T_C = 125^\circ\text{C}$	
UES2601/2601HR2 UES2602/2602HR2 UES2603/2603HR2	50V 100V 150V	.930V @ 15A $t_p = 300\mu\text{S}$	.825V @ 15A $t_p = 300\mu\text{S}$	20 μA	4mA	35nS

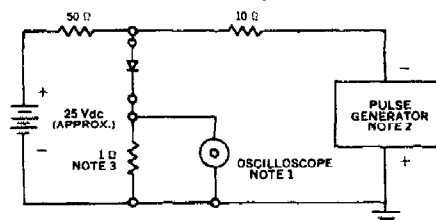
* Measured in circuit $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $I_{\text{REC}} = 0.25\text{A}$



UES2601 UES2602 UES2603
UES2601HR2 UES2602HR2 UES2603HR2



Reverse-Recovery Circuit



- NOTES:**
1. Oscilloscope: Rise time ≤ 3 ns; input impedance = 500.
 2. Pulse Generator: Rise time ≤ 8 ns; source impedance 100.
 3. Current viewing resistor, non-inductive, coaxial recommended.

OPTIONAL HIGH RELIABILITY (HR2) SCREENING

The following tests are performed on 100% of the devices specified UES2601HR2, 2HR2, 3HR2.

SCREEN	MIL-STD-750 METHOD	CONDITIONS
1. High Temperature	1032	24 Hours @ $T_A = 150^\circ\text{C}$
2. Thermal Shock (Temperature Cycling)	1051	F, 20 Cycles, -55 to $+150^\circ\text{C}$. No dwell required @ 25°C , $t \geq 10$ min. at extremes.
3. Hermetic Seal a. Fine b. Gross	1071	H, Helium C, Liquid
4. Thermal Impedance		Sage Test
5. Interim Electrical Parameters	GO/NO GO	V_F and I_R @ 25°C
6. High Temperature Reverse Bias (HTRB)	1038	A, 48 Hours, $T_C = 125^\circ\text{C}$, $V_R = 80\%$ of rating
7. Final Electrical Parameters	GO/NO GO	V_F and I_R @ 25°C